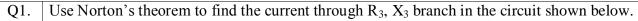
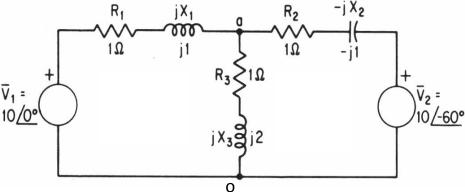
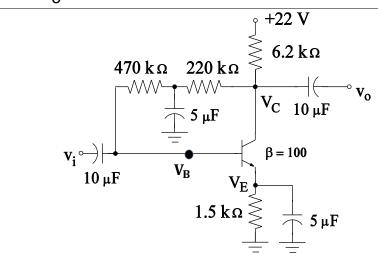
EE101 Tutorial-5 (11 Sep 2014)



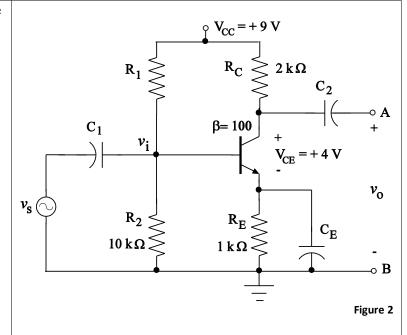


- Q2. For the transistor amplifier circuit with collector-emitter feedback biasing shown in Figure 1, find the value of
 - a. I_B
 - b. V_C
 - c. V_E
 - d. V_{CE}

(Assume that $V_{BE} = 0.7 V$ in forward biased condition)



- Figure 1
- Q3. In Figure 2, the transistor is in active region with the quiescent C-E voltage $V_{CEQ} = 4 V$. Assume that $V_{BE} = 0.7 V$, $V_T = 26 mV$, BJT output resistance r_o is very high (> 100 k Ω), and all capacitors are short-circuited at applied signal frequency. Find the value of
 - a. R_1
 - b. *r_e*
 - c. $A_v = \frac{v_o}{v_i}$
 - d. A_v , if a load $R_L = 2 k\Omega$ is
 - connected across A-B. e. $A_{v_s} = \frac{v_o}{v_s}$, if $R_L = 2 k\Omega$ is connected across A-B and assuming that applied voltage source has a resistance of $R_s = 0.5 k\Omega$.



EE101 Tutorial-5 (11 Sep 2014) Solutions

Q1. Impedance between the terminals a-o,

$$Z_N = (R_1 + jX_1) | | (R_2 - jX_2)$$

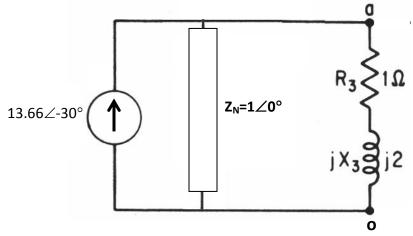
Therefore,

$$Z_N = \frac{(1+j1)}{(1-j1)} = \frac{\sqrt{2} \angle 45^{\circ} \times \sqrt{2} \angle -45^{\circ}}{1+j1+1-j1} = 1 \angle 0^{\circ} \Omega$$

Short circuit current across a-o,

$$I_{sc} = \frac{V_1}{R_1 + jX_1} + \frac{V_2}{R_2 - jX_2} = \frac{10\angle 0^{\circ}}{1 + j1} + \frac{10\angle -60^{\circ}}{1 - j1} = 5\sqrt{2}\angle -45^{\circ} + 5\sqrt{2}\angle -15^{\circ}$$
$$= 6.83 - j1.83 + 5 - j5 = 11.83 - j6.83$$
$$= 13.66\angle -30^{\circ} \text{ A}$$

The Norton's equivalent circuit is as shown below,

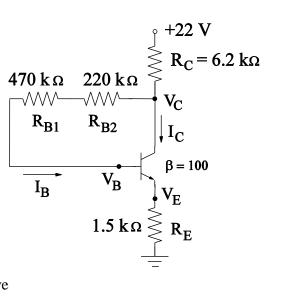


And the current through R_3 , X_3 is computed as:

$$I_3$$
 = $I_{sc} \times \frac{1 \angle 0^{\circ}}{1 \angle 0^{\circ} + 1 + j2}$ = $13.661 \angle -30^{\circ} \times \frac{1}{2\sqrt{2}\angle 45^{\circ}}$
= $4.83 \angle -75^{\circ}$ A

Q2. For determining the dc current and voltages, the DC-equivalent circuit for the given transistor amplifier is shown below.

In the given circuit V_B is expected is higher than V_E , so the B-E junction would be forward biased and we assume that the transistor is in **active region** of operation, i.e., $I_C = \beta I_B$



(a) On applying KVL in the input (base) loop we have

$$V_{CC} = I_B(R_{B1} + R_{B2}) + V_{BE} + (I_B + I_C)(R_C + R_E)$$

$$I_B = \frac{V_{CC} - V_{BE}}{(R_{B1} + R_{B2}) + (\beta + 1)(R_C + R_E)}$$

$$I_B = \frac{22 V - 0.7 V}{(470 k\Omega + 220 k\Omega) + 101(6.2 k\Omega + 1.5 k\Omega)} \cong 14.51 \,\mu A$$

(b)
$$V_C = V_{CC} - (\beta + 1)I_B R_C = 22 V - 101 \times 14.51 \ \mu A \times 6.2 \ k\Omega$$

= 22 V - 9.09 V
= 12.91 V

(c)
$$V_E = (\beta + 1)I_B R_E = 101 \times 14.51 \,\mu A \times 1.5 \,k\Omega \cong 2.20 \,V$$

(d)
$$V_{CE} = V_C - V_E = 12.91 V - 2.20 V = 10.71 V$$

Check: $V_B = V_E + 0.7 V = 2.9 V$ and so $V_{CB} = 12.91 V - 2.9 V = 10.01 V$. Thus C-B junction is reversed biased and assumption about transistor being in active region is valid.

- Q3. Given that $V_{CEQ} = 4 V$ and the transistor is in active region, so $I_C = \beta I_B$
 - (a) On applying KCL in the output (collector) loop, we have

$$V_{CC} = I_C R_C + V_{CEQ} + I_E R_E = I_C R_C + V_{CEQ} + \left(1 + \frac{1}{\beta}\right) I_C R_E$$

$$I_C = \frac{V_{CC} - V_{CEQ}}{R_C + \left(1 + \frac{1}{\beta}\right)R_E} = \frac{9 V - 4 V}{2 \text{ k}\Omega + 1.01 \times 1 \text{ k}\Omega} = 1.66 \text{ mA}$$

and

$$I_B = \frac{I_C}{\beta} = \frac{1.66 \ mA}{100} = 0.0166 \ mA$$

For the voltage-divider biasing, find the Thevenin's equivalent as seen by B-E terminals of BJT as

$$V_{Th} = \left(\frac{9 \times 10 \ k\Omega}{10 \ k\Omega + R_1}\right) V$$
 and $R_{Th} = (10 \ k \parallel R_1) \ \Omega$

Now applying KVL in the input (base) loop, we have

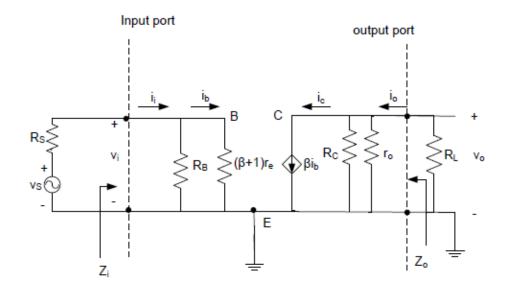
$$\left(\frac{9 \times 10 \ k\Omega}{10 \ k\Omega + R_1}\right) V = \left(\frac{R_1 \times 10 \ k\Omega}{10 \ k\Omega + R_1}\right) I_B + V_{BE} + (1 + \beta) I_B R_E$$

$$\left(\frac{90 \ k\Omega - 0.166 R_1}{10 \ k\Omega + R_1}\right) V = 0.7 \ V + 101(0.0166 \ mA \times 1k\Omega) \cong 2.38 \ V$$

$$90 \ k\Omega - 0.166 R_1 = 23.8 \ k\Omega + 2.38 R_1 \quad \Rightarrow \quad R_1 = \frac{66.2 \ k\Omega}{2.546} = 26 \ k\Omega$$

(b)
$$I_E = (1 + \beta)I_B \cong 1.68 \text{ mA}$$
, so $r_e = \frac{26 \text{ mV}}{I_E} = \frac{26 \text{ mV}}{1.68 \text{ mA}} \cong 15.5 \Omega$

The AC equivalent circuit of the given amplifier circuit (Given for reference purpose only)



(c) Using the derived expression, the voltage gain,

$$A_v = \frac{v_o}{v_i} = -\frac{R_C \parallel r_o}{r_e} \cong -\frac{R_C}{r_e} = -\frac{2 \ k\Omega}{15.5 \ \Omega} = -129$$

(d) The voltage gain with load R_L connected across A-B,

$$A'_{v} = -\frac{R_{C} \parallel R_{L}}{r_{e}} = -\frac{2 k\Omega \parallel 2 k\Omega}{15.5 \Omega} = -64.5$$

(e) The voltage gain of amplifier with source resistance R_s and load resistance R_L included, is derived as below (the below material is copied from that in slides)

$$\frac{v_{Ai}}{v_s} = \frac{Z_i}{Z_i + R_s} \qquad \frac{v_o}{v_{Ao}} = \frac{R_L}{R_L + Z_o}$$

$$A_v^* = \frac{v_o}{v_s} = \frac{v_o}{v_{Ao}} \frac{v_{Ao}}{v_{Ai}} \frac{v_{Ai}}{v_s}$$

$$= \frac{R_L}{R_L + Z_o} A_v \frac{Z_i}{Z_i + R_s}$$

$$A_{v_S} = \frac{v_o}{v_S} = \frac{Z_i}{R_S + Z_i} \times A_v \times \frac{R_L}{Z_o + R_L}$$

where Z_i is the input resistance and Z_o is the output resistance of amplifier, respectively

$$Z_i = (R_1 \parallel R_2) \parallel (\beta + 1)r_e = (26 \ k\Omega \parallel 10 \ k\Omega) \parallel (101 \times 15.5 \ \Omega) \cong 1.29 \ k\Omega$$

$$Z_o \cong R_C = 2 \ k\Omega$$

$$A_{v_s} = \frac{1.29 \ k\Omega}{0.5 \ k\Omega + 1.29 \ k\Omega} \times (-129) \times \frac{2 \ k\Omega}{2 \ k\Omega + 2 \ k\Omega} \cong -46.5$$

Note for the reduction in the overall gain of the amplifier due to inclusion of load resistance and/or source resistance.